

SN54ABT16265, SN74ABT16265 12-BIT TO 24-BIT MULTIPLEXED TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS468 – JUNE 1992–REVISED OCTOBER 1992

- Members of the Texas Instruments *Widebus™* Family
- State-of-the-Art *EPIC-II B™* BiCMOS Design Significantly Reduces Power Dissipation
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- High-Drive Outputs (–32-mA I_{OH} , 64-mA I_{OL})
- Bus-Hold Inputs Eliminate the Need for External Pullup Resistors
- Packaged in Plastic 300-mil Shrink Small-Outline Packages (DL) and 380-mil Fine-Pitch Ceramic Flat Packages (WD) Using 25-mil Center-to-Center Spacings

description

The 'ABT16265 is a 12-bit to 24-bit multiplexed transceiver used in applications where two separate data paths must be multiplexed onto, or demultiplexed from, a single data path. Typical applications include multiplexing and/or demultiplexing of address and data information in microprocessor- or bus-interface applications. This device is also useful in memory-interleaving applications.

Three 12-bit I/O ports (A1–A12, 1B1–1B12, and 2B1–2B12) are available for address and/or data transfer. The output-enable ($\overline{OE1B}$, $\overline{OE2B}$, and $\overline{OE A}$) inputs control the bus transceiver functions. These control signals also allow byte-control of the most significant byte and least significant byte for each bus.

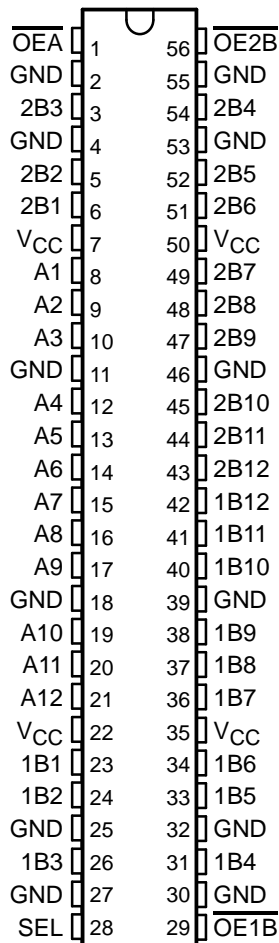
Active bus-hold circuitry is provided to hold unused or floating inputs at a valid logic level.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74ABT16265 is packaged in TI's shrink small-outline package (DL), which provides twice the I/O pin count and functionality of standard small-outline packages in the same printed-circuit-board area.

The SN54ABT16265 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ABT16265 is characterized for operation from -40°C to 85°C .

SN54ABT16265 . . . WD PACKAGE
SN74ABT16265 . . . DL PACKAGE
(TOP VIEW)



PRODUCT PREVIEW

Widebus and EPIC-II B are trademarks of Texas Instruments Incorporated.

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265
POST OFFICE BOX 1443 • HOUSTON, TEXAS
77251-1443

Copyright © 1992, Texas Instruments Incorporated

JUNE 1992—REVISED OCTOBER 1992

INPUTS				OUTPUT A
1B	2B	SEL	<u>OEA</u>	
H	X	H	L	H
L	X	H	L	L
X	H	L	L	H
X	L	L	L	L
X	X	X	H	Z

INPUTS			OUTPUTS	
A	$\overline{OE1B}$	$\overline{OE2B}$	1B	2B
H	L	L	H	H
L	L	L	L	L
X	H	H	Z	Z
X	L	H	Active	Z
X	H	L	Z	Active
X	L	L	Active	Active

To 11 Other Channels

SN54ABT16265, SN74ABT16265
12-BIT TO 24-BIT MULTIPLEXED TRANSCEIVERS
WITH 3-STATE OUTPUTS
 JUNE 1992—REVISED OCTOBER 1992

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	−0.5 V to 7 V
Input voltage range, V_I (see Note 1)	−0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, V_O	−0.5 V to 5.5 V
Current into any output in the low state, I_O : SN54ABT16265	96 mA
SN74ABT16265	128 mA
Input clamp current, I_{IK} ($V_I < 0$)	−18 mA
Output clamp current, I_{OK} ($V_O < 0$)	−50 mA
Maximum power dissipation at $T_A = 55^\circ\text{C}$ (in still air)	1 W
Storage temperature range	−65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions

		SN54ABT16265		SN74ABT16265		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		−24		−32	mA
I_{OL}	Low-level output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled			10	ns/V
T_A	Operating free-air temperature	−55	125	−40	85	°C

PRODUCT PREVIEW



SN54ABT16265, SN74ABT16265

12-BIT TO 24-BIT MULTIPLEXED TRANSCEIVERS

WITH 3-STATE OUTPUTS

JUNE 1992–REVISED OCTOBER 1992

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		T _A = 25°C			SN54ABT16265		SN74ABT16265		UNIT
			MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V _{IK}	V _{CC} = 4.5 V, I _I = -18 mA				-1.2		-1.2		-1.2	V
V _{OH}	V _{CC} = 4.5 V, I _{OH} = -3 mA		2.5			2.5		2.5		V
	V _{CC} = 5 V, I _{OH} = -3 mA		3			3		3		
	V _{CC} = 4.5 V, I _{OH} = -24 mA		2			2				
	V _{CC} = 4.5 V, I _{OH} = -32 mA		2‡					2		
V _{OL}	V _{CC} = 4.5 V, I _{OL} = 48 mA				0.55		0.55			V
	V _{CC} = 4.5 V, I _{OL} = 64 mA				0.55‡			0.55		
I _I	V _{CC} = 5.5 V, V _I = V _{CC} or GND	Control inputs			±1		±1		±1	µA
		A or B ports			±100		±100		±100	
I _{hold}	V _{CC} = 4.5 V, V _I = 0.8 V	A or B ports						100		µA
	V _{CC} = 4.5 V, V _I = 2 V							-100		
I _{OZH} §	V _{CC} = 5.5 V, V _O = 2.7 V				50		50		50	µA
I _{OZL} §	V _{CC} = 5.5 V, V _O = 0.5 V				-50		-50		-50	µA
I _{OFF}	V _{CC} = 0 V, V _I or V _O ≤ 4.5 V				±100				±100	µA
I _{CEX}	V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50		50		50	µA
I _O ¶	V _{CC} = 5.5 V, V _O = 2.5 V		-50	-100	-180	-50	-180	-50	-180	mA
I _{CC}	V _{CC} = 5.5 V, I _O = 0, V _I = V _{CC} or GND	A or B ports								mA
		Outputs high			3		3		3	
		Outputs low			60		60		60	
ΔI _{CC} #	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND	Data inputs								mA
		Control inputs								
C _i	V _I = 2.5 V or 0.5 V	Control inputs								pF
C _{io}	V _O = 2.5 V or 0.5 V	A or B ports								pF

† All typical values are at V_{CC} = 5 V.

‡ On products compliant to MIL-STD-883, Class B, this parameter does not apply.

§ The parameters I_{OZH} and I_{OZL} include the input leakage current.

¶ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

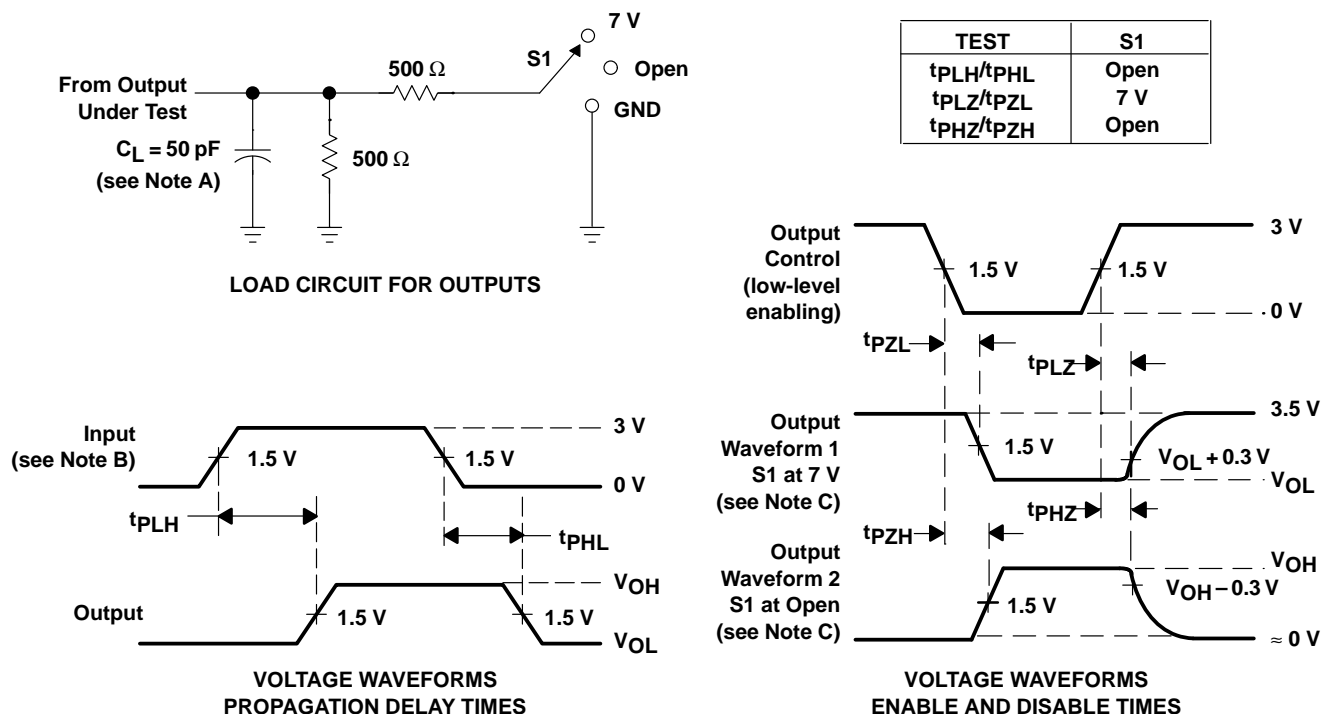
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			SN54ABT16265		SN74ABT16265		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A or B	B or A								ns
t _{PHL}										
t _{PLH}	SEL	A								ns
t _{PHL}										
t _{PZH}	OE	A or B								ns
t _{PZL}										
t _{PHZ}	OE	A or B								ns
t _{PLZ}										

PRODUCT PREVIEW



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265
POST OFFICE BOX 1443 • HOUSTON, TEXAS 77251-1443

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

IMPORTANT NOTICE

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.